
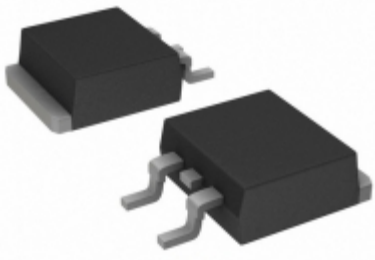


	<h2 style="color: red;">FQB9N25TM</h2>
	<p>Hersteller-Teilenummer: FQB9N25TM</p> <hr/> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 250V 9.4A D2PAK</p> <hr/> <p>Datenblätter:  FQB9N25TM.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 760 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQB9N25TM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 250V 9.4A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	760 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 90W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	250V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	9.4A (Tc)
Rds On (Max) @ Id, Vgs	420 mOhm @ 4.7A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	20nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	700pF @ 25V
Verpackung	Tape & Reel (TR)



















































FQB9N25TM ist neu im Original, Suche FQB9N25TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB9N25TM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB9N25TM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB9N25TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 9.4A D2PAK</p>	 <p>FQB9N25C Fairchild/ON Semiconductor FQB9N25C FAIRCHILD</p>	 <p>FQB9N25CTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 8.8A D2PAK</p>	 <p>FQB9N25 Fairchild/ON Semiconductor FQB9N25 FAIRCHILD</p>
 <p>FQB9N50CFTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 9A D2PAK</p>	 <p>FQB9N50CFTM Fairchild/ON Semiconductor MOSFET N-CH 500V 9A D2PAK</p>	 <p>FQB9N50C FAIRCHI FQB9N50C FAIRCHI</p>	 <p>FQB9N50 FSC FQB9N50 FSC</p>

heiße Teile

Mehr

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|---|--|---|---|---|
|  FQB6N70TM |  FQB6N90TM |  FQB6N90TM_AM002 |  FQB6N90TM_AM002 |  FQB7042FB |
|  FQB7045FB |  FQB70N03 |  FQB70N06 |  FQB70N08 |  FQB70N10TM |
|  FQB7N10L |  FQB7N20L |  FQB7N60TM |  FQB7N60TM |  FQB7N65C |
|  FQB7N65CTM |  FQB7N65CTM |  FQB7P20TM |  FQB7P20TM |  FQB85N06 |
|  FQB85N06TM |  FQB8N25TM |  FQB8N25TM |  FQB8N60C |  FQB8N60CFTM |
|  FQB8N60CFTM |  FQB8N60CTM |  FQB8N60CTM |  FQB8N60TM |  FQB8N90CTM |
|  FQB8N90CTM |  FQB8P10TM |  FQB8P10TM |  FQB8P10TM-NL |  FQB9N08L |
|  FQB9N08LTM |  FQB9N08LTM |  FQB9N25C |  FQB9N25CTM |  FQB9N25CTM |
|  FQB9N25TM |  FQB9N50C |  FQB9N50CFTM |  FQB9N50CFTM |  FQB9N50CTM |
|  FQB9N50CTM |  FQB9N50TM |  FQB9N50TM |  FQB9P25TM |  FQB9P25TM |

Contact us: Info@Y-IC.com

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